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# BAP1321LX

Silicon PIN diode

Rev. 2 — 7 August 2013

Product data sheet

## 1. Product profile

### 1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

### 1.2 Features and benefits

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 3 GHz

### 1.3 Applications

- RF attenuators and switches

## 2. Pinning information

Table 1. Discrete pinning

| Pin | Description | Simplified outline       | Symbol            |
|-----|-------------|--------------------------|-------------------|
| 1   | cathode     | <a href="#">[1]</a>      | <br><i>sym006</i> |
| 2   | anode       | <br>Transparent top view |                   |

[1] The marking bar indicates the cathode.

## 3. Ordering information

Table 2. Ordering information

| Type number | Package    |  |         |
|-------------|------------|--|---------|
|             | Name       | Description  | Version |
| BAP1321LX   | DFN1006D-2 | leadless ultra small plastic package; 2 terminals; body 1 × 0.6 × 0.4 mm | SOD882D |



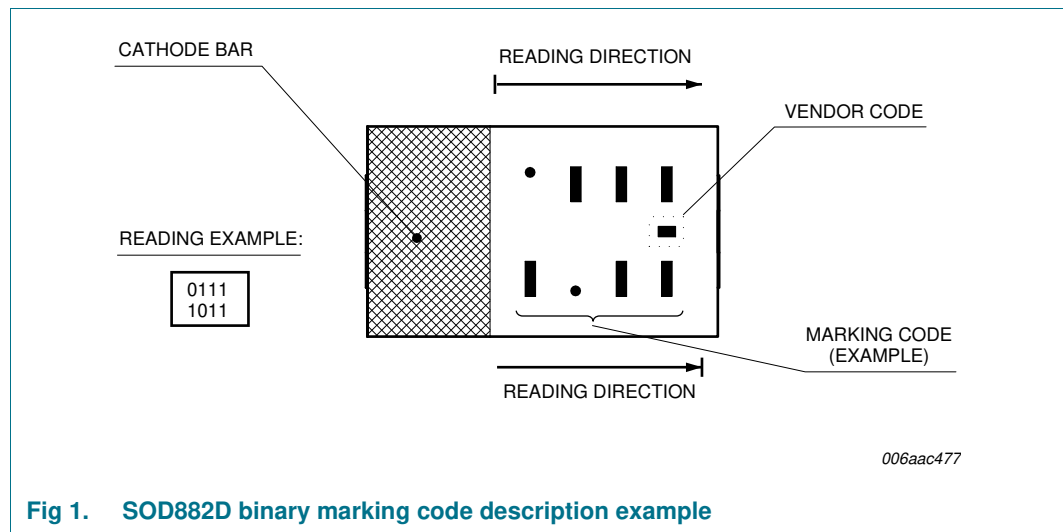
## 4. Marking

**Table 3. Marking codes**

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| BAP1321LX   | 1001<br>0001                |

[1] For SOD882D binary marking code description, see [Figure 1](#).

### 4.1 Binary marking code description



## 5. Limiting values

**Table 4. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol    | Parameter               | Conditions              | Min | Max  | Unit |
|-----------|-------------------------|-------------------------|-----|------|------|
| $V_R$     | reverse voltage         |                         | -   | 60   | V    |
| $I_F$     | forward current         |                         | -   | 100  | mA   |
| $P_{tot}$ | total power dissipation | $T_{sp} = 90\text{ °C}$ | -   | 130  | mW   |
| $T_{stg}$ | storage temperature     |                         | -65 | +150 | °C   |
| $T_j$     | junction temperature    |                         | -65 | +150 | °C   |

## 6. Thermal characteristics

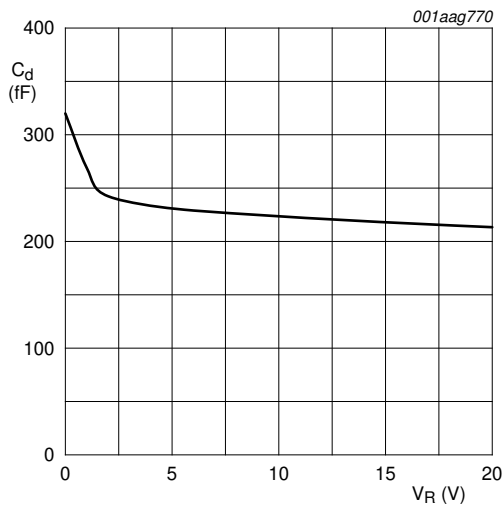
**Table 5. Thermal characteristics**

| Symbol         | Parameter  | Conditions | Typ | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |            | 74  | K/W  |

## 7. Characteristics

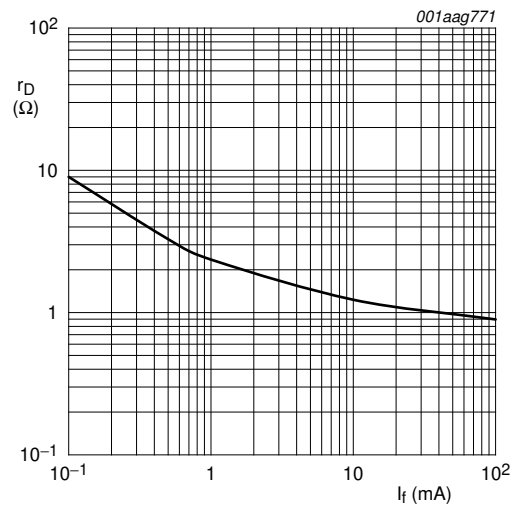
**Table 6. Characteristics**
*T<sub>amb</sub> = 25 °C unless otherwise specified.*

| Symbol           | Parameter                | Conditions  | Min | Typ  | Max  | Unit |
|------------------|--------------------------|---|-----|------|------|------|
| V <sub>F</sub>   | forward voltage          | I <sub>F</sub> = 50 mA  | -   | 0.95 | 1.1  | V    |
| I <sub>R</sub>   | reverse current          | V <sub>R</sub> = 60 V   | -   | -    | 100  | nA   |
| C <sub>d</sub>   | diode capacitance        | see <a href="#">Figure 2</a> ; f = 1 MHz;   |     |      |      |      |
|                  |                          | V <sub>R</sub> = 0 V  | -   | 0.32 | -    | pF   |
|                  |                          | V <sub>R</sub> = 1 V  | -   | 0.27 | 0.38 | pF   |
|                  |                          | V <sub>R</sub> = 20 V   | -   | 0.21 | 0.28 | pF   |
| r <sub>D</sub>   | diode forward resistance | see <a href="#">Figure 3</a> ; f = 100 MHz;   |     |      |      |      |
|                  |                          | I <sub>F</sub> = 0.5 mA   | -   | 3.3  | 5.0  | Ω    |
|                  |                          | I <sub>F</sub> = 1 mA   | -   | 2.4  | 3.6  | Ω    |
|                  |                          | I <sub>F</sub> = 10 mA  | -   | 1.2  | 1.8  | Ω    |
|                  |                          | I <sub>F</sub> = 100 mA   | -   | 0.9  | 1.3  | Ω    |
| ISL              | isolation                | see <a href="#">Figure 4</a> ; V <sub>R</sub> = 0 V;  |     |      |      |      |
|                  |                          | f = 900 MHz   | -   | 17   | -    | dB   |
|                  |                          | f = 1800 MHz  | -   | 12   | -    | dB   |
|                  |                          | f = 2450 MHz  | -   | 10   | -    | dB   |
| L <sub>ins</sub> | insertion loss           | see <a href="#">Figure 5</a> ; I <sub>F</sub> = 0.5 mA;   |     |      |      |      |
|                  |                          | f = 900 MHz   | -   | 0.25 | -    | dB   |
|                  |                          | f = 1800 MHz  | -   | 0.26 | -    | dB   |
|                  |                          | f = 2450 MHz  | -   | 0.27 | -    | dB   |
| L <sub>ins</sub> | insertion loss           | see <a href="#">Figure 5</a> ; I <sub>F</sub> = 1 mA;   |     |      |      |      |
|                  |                          | f = 900 MHz   | -   | 0.19 | -    | dB   |
|                  |                          | f = 1800 MHz  | -   | 0.20 | -    | dB   |
|                  |                          | f = 2450 MHz  | -   | 0.21 | -    | dB   |
| L <sub>ins</sub> | insertion loss           | see <a href="#">Figure 5</a> ; I <sub>F</sub> = 10 mA;  |     |      |      |      |
|                  |                          | f = 900 MHz   | -   | 0.11 | -    | dB   |
|                  |                          | f = 1800 MHz  | -   | 0.13 | -    | dB   |
|                  |                          | f = 2450 MHz  | -   | 0.14 | -    | dB   |
| L <sub>ins</sub> | insertion loss           | see <a href="#">Figure 5</a> ; I <sub>F</sub> = 100 mA;   |     |      |      |      |
|                  |                          | f = 900 MHz   | -   | 0.09 | -    | dB   |
|                  |                          | f = 1800 MHz  | -   | 0.11 | -    | dB   |
|                  |                          | f = 2450 MHz  | -   | 0.12 | -    | dB   |
| τ <sub>L</sub>   | charge carrier life time | when switched from I <sub>F</sub> = 10 mA to I <sub>R</sub> = 6 mA; R <sub>L</sub> = 100 Ω; measured at I <sub>R</sub> = 3 mA | -   | 0.48 | -    | μs   |
| L <sub>S</sub>   | series inductance        | I <sub>F</sub> = 100 mA; f = 100 MHz  | -   | 0.4  | -    | nH   |



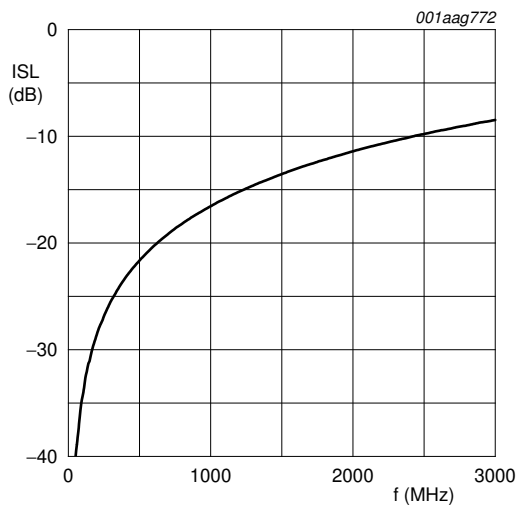
$f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C}.$

**Fig 2. Diode capacitance as a function of reverse voltage; typical values**



$f = 100 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C}.$

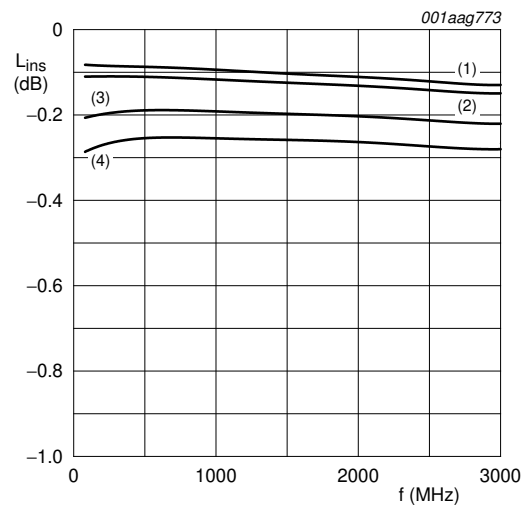
**Fig 3. Forward resistance as a function of forward current; typical values**



$T_{amb} = 25 \text{ }^\circ\text{C}$

Diode zero biased and inserted in series with a  $50 \text{ } \Omega$  stripline circuit

**Fig 4. Isolation of the diode as a function of frequency; typical values**



$T_{amb} = 25 \text{ }^\circ\text{C}$

- (1)  $I_F = 100 \text{ mA}$
- (2)  $I_F = 10 \text{ mA}$
- (3)  $I_F = 1 \text{ mA}$
- (4)  $I_F = 0.5 \text{ mA}$

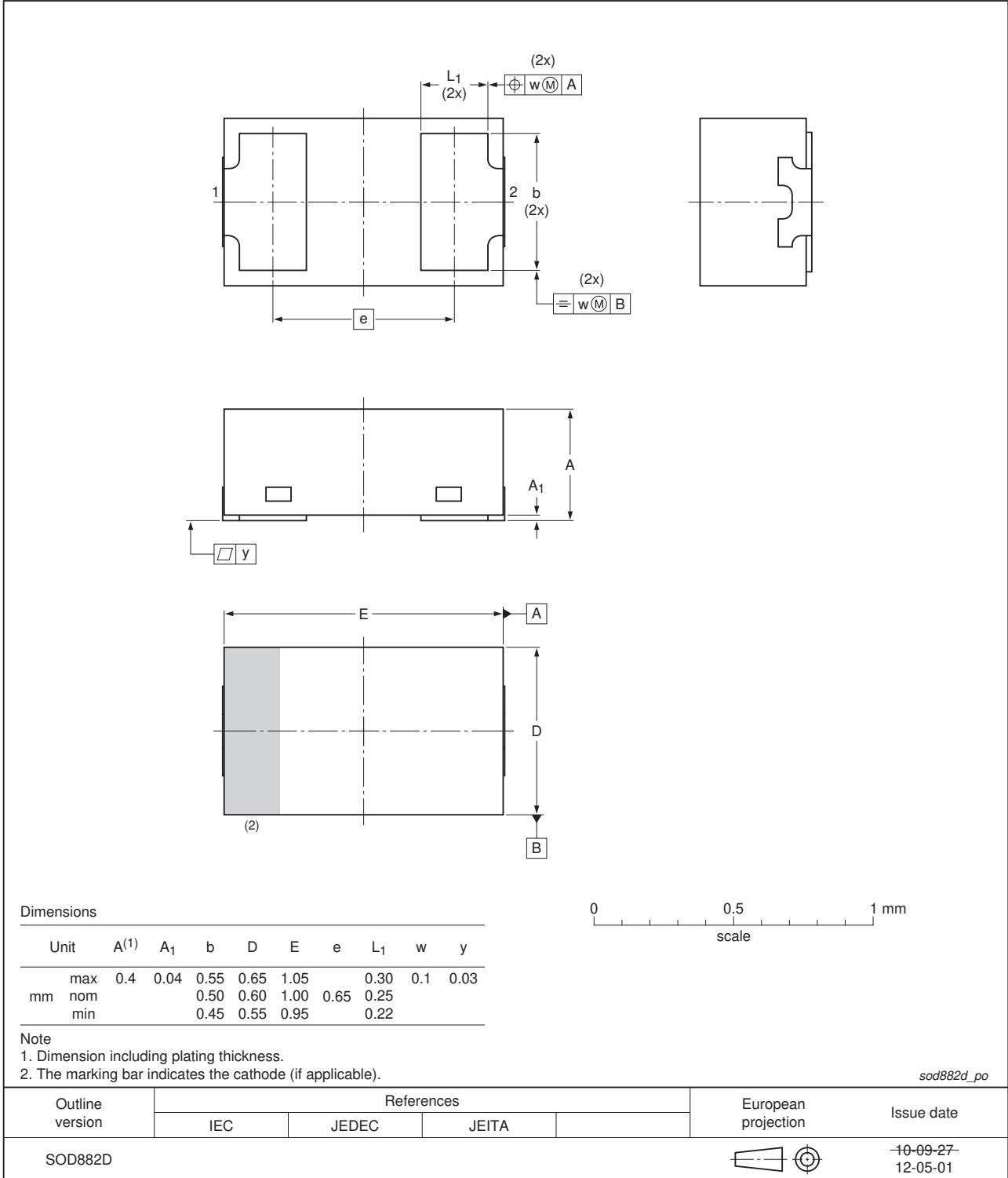
Diode inserted in series with a  $50 \text{ } \Omega$  stripline circuit and biased via the analyzer Tee network

**Fig 5. Insertion loss of the diode as a function of frequency; typical values**

**8. Package outline**

DFN1006D-2: Leadless ultra small plastic package; 2 terminals; body 1 x 0.6 x 0.4 mm

SOD882D



**Fig 6. Package outline SOD882D (DFN1006D-2)**

## 9. Abbreviations

Table 7. Abbreviations

| Acronym | Description               |
|---------|---------------------------|
| PIN     | P-type, Intrinsic, N-type |
| SMD     | Surface Mounted Device    |
| RF      | Radio Frequency           |

## 10. Revision history

Table 8. Revision history

| Document ID    | Release date | Data sheet status  | Change notice | Supersedes    |
|----------------|--------------|--|---------------|---------------|
| BAP1321LX v.2  | 20130807     | Product data sheet   | -             | BAP1321LX v.1 |
| Modifications: |              | <ul style="list-style-type: none"><li>• <a href="#">Section 1.1 on page 1</a>: Changed package to SOD882D</li><li>• <a href="#">Table 1 on page 1</a>: Changed simplified outline to SOD882D</li><li>• <a href="#">Table 2 on page 1</a>: Changed package to SOD882D</li><li>• <a href="#">Section 4 on page 2</a>: Update 'Marking' section</li><li>• <a href="#">Section 8 on page 5</a>: Changed package to SOD882D</li></ul> |               |               |
| BAP1321LX v.1  | 20070730     | Product data sheet   | -             | -             |

## 11. Legal information

### 11.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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